

Schottky Dual Diode

MBRF1545CT

45V / 15A

DATASHEET

from

www.web-bcs.com

OEM – General Semiconductor

Source: General Semiconductor Databook 1998

NEW PRODUCT

NEW PRODUCT

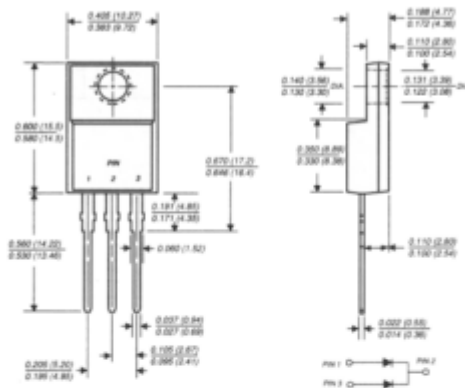
NEW PRODUCT

MBRF1535CT THRU MBRF1560CT

SCHOTTKY RECTIFIER

Reverse Voltage - 35 to 60 Volts Forward Current - 15.0 Amperes

ITO-220AB



Dimensions in inches and (millimeters)

FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Dual rectifier construction, positive center tap
- ◆ Guardring for transient protection
- ◆ High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case



MECHANICAL DATA

Case: ITO-220AB molded plastic body
Terminals: Leads solderable per MIL-STD-750, Method 2026
Polarity: As marked
Mounting Position: Any
Mounting Torque: 5 in. - lbs. max.
Weight: 0.08 ounces, 2.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	MBRF1535CT	MBRF1545CT	MBRF1550CT	MBRF1560CT	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50	60	Volts
Maximum working peak reverse voltage	V _{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage	V _{DC}	35	45	50	60	Volts
Maximum average forward rectified current at T _C =105°C	I _(AV)	15.0				Amps
Peak repetitive forward current at T _C =105°C per diode (rated V _R , 20KHz sq.wave)	I _{FRM}	15.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0				Amps
Peak repetitive reverse surge current (NOTE 1)	I _{RRM}	1.0		0.5		Amps
Maximum instantaneous forward voltage per leg at (NOTE 2)	V _F	I _F =7.5A, T _C =25°C I _F =7.5A, T _C =125°C I _F =15A, T _C =25°C I _F =15A, T _C =125°C		0.75 0.65 - -		Volts
Maximum instantaneous reverse current at rated DC blocking voltage per leg (NOTE 2) T _C =125°C	I _R	0.1 15.0		1.0 50.0		mA
Voltage rate of change, (rated V _R)	dv/dt	10,000				V/μs
Maximum thermal resistance per leg (NOTE 3)	R _{θJC}	5.0				°C/W
Operating junction temperature range	T _J	-65 to +150				°C
Storage temperature range	T _{STG}	-65 to +175				°C

NOTES: (1) 2.0μs pulse width, f=1.0 KHz
 (2) 300μs, pulse width, 1% duty cycle
 (3) Thermal resistance from junction to case

RATINGS AND CHARACTERISTIC CURVES MBRF1535CT THRU MBRF1560CT

